

INFORMATION DISCLOSURE STATEMENT

Applicant	:	Fulkerson, et al.
App. No.	:	Unknown
Filed	:	Herewith
For	:	BRIDGE-TYPE MAGNETIC RANDOM ACCESS MEMORY (MRAM) LATCH
Examiner	:	Unknown
Group Art Unit	:	Unknown

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Enclosed is form PTO-1449 and form PTO-892 listing 8 references that are of record in U.S. patent application No. 10/246,245, filed September 17, 2002, which is the parent of this continuation application, and is relied upon for an earlier filing date under 35 U.S.C. § 120. Copies of the references are not submitted pursuant to 37 C.F.R. § 1.98(d).

This Information Disclosure Statement is being filed within three months of the filing date of this application and no fee is required in accordance with 37 C.F.R. § 1.97(b)(1).

Respectfully submitted,

KNOBBE, MARTENS, OLSON & BEAR, LLP

Dated: February 10, 2004

By: Michael S. Okamoto

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FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT (USE SEVERAL SHEETS IF NECESSARY)	ATTY. DOCKET NO. MICRON.221C1	APPLICATION NO. Unknown
	APPLICANT Fulkerson, et al.	
	FILING DATE Herewith	GROUP Unknown

U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)

FOREIGN PATENT DOCUMENTS								
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO

EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)
	Daughton, James M., "Advanced MRAM Concepts" 2/7/01 <u>NVE Cooperation</u> retrieved from the Internet: <URL: www.nve.com/otherbiz/mram.pdf> retrieved on January 25, 2002
	Lee, et al., "Separation of Contributions to Spin Valve Interlayer Exchange Coupling Field by Temperature Dependent Coupling Field Measurements" [online] 46 th MMM Conference Seattle, Washington 2001 pp. 1-16 [retrieved on January 25, 2002] Retrieved from the Internet: <URL:www.andrew.cmu.edu/~zlee/mmm.pdf>
	"Magnetoelectronics" [online] [retrieved on January 25, 2002] Retrieved from the Internet: <URL: www.ipm.virginia.edu/research/PVD/Pubs/thesis7/chapter2.PDF> Chapter 2 pp. 7-34
	"Non-Volatile Memory (MRAM)" <u>ANXXX</u> [online] Honeywell <retrieved on November 19, 2001> <URL: www.ssec.honeywell.com/avionics/h_gmr.pdf> pp. 1-4

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EXAMINER	DATE CONSIDERED
*EXAMINER: INITIAL IF CITATION CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAW LINE THROUGH CITATION IF NOT IN CONFORMANCE AND NOT CONSIDERED, INCLUDE COPY OF THIS FORM WITH NEXT COMMUNICATION TO APPLICANT.	

Notic of References Cited

Application/Control No.

10/246,245

Applicant(s)/Patent Under
Reexamination
FULKERSON ET AL.

Examiner

Thong Q. Le

Art Unit

2818

Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
✓	A	US-6,343,032 ✓	01-2002	Black et al.	365/158
✓	B	US-6,317,359 ✓	11-2001	Black et al.	365/158
✓	C	US-6542000 ✓	04-2003	Black et al.	326/39
✓	D	US-2002/0064067 ✓	05-2002	Inui, Fumihito	365/158
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	
	V	
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.